NSN 5961-01-391-8014

A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-391-8014 **Inclosure Material:** Metal **Overall Length:** Between 0.189 inches and 0.205 inches **Overall Diameter:** Between 0.094 inches and 0.105 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-213ab **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 45.0 working peak reverse voltage **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead **Specification Data:** 81349-mil-s-19500/586 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: